

Green Products

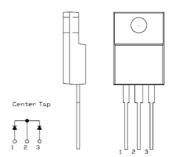
MBRF3060CTP SCHOTTKY RECTIFIER

Applications:

• Switching power supply • Converters • Free-Wheeling diodes • Reverse battery protection

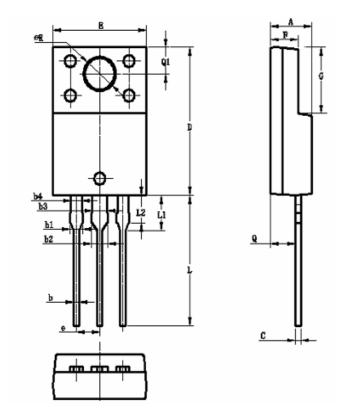
Features:

- 150 °C T J operation
- Center tap configuration
- Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- High frequency operation
- · Guard ring for enhanced ruggedness and long term reliability
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request



OUTLINE DRAWING

Mechanical Dimensions: In mm



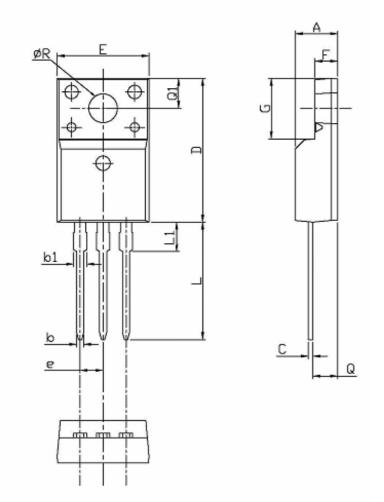
	OPTION 1(CJ)		OPTIO	N 2(HD)
Dim	Min	Max	Min	Max
Α	4.4	4.6	4.30	4.70
b	0.61	ΥP	0.50	0.75
b1	1.3T	ΥP	1.30	1.40
b2	1.71	ΥP	1.70	1.80
b3	1.6T	ΥP	1.50	1.75
b4	1.2T	ΥP	1.10	1.35
С	0.60	TYP	0.50	0.75
D	14.8	15.1	14.80	15.20
E	10.06	10.26	9.96	10.36
е	2.55TYP		2.54TYP	
F	2.9 3.1		2.80	3.20
G	6.5	6.9	6.50	6.90
L	12.7	13.7	12.8	13.2
L1	3.4	3.8	3.60	4.00
L2	2.6	3.0	-	-
Q	2.5	2.9	2.50	2.90
Q1	2.5	2.9	2.70REF	
ØR	3.5REF		3.50	REF

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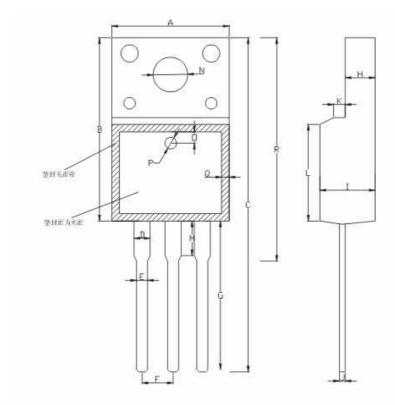


	OPTION 3		OPTION 4	
Dim	Min	Max	Min	Max
Α	4.53	4.93	4.50	4.90
b	0.71	0.91	0.70	0.90
b1	1.15	1.39	1.33	1.47
С	0.36	0.53	0.45	0.60
D	15.67	16.07	15.67	16.07
E	9.96	10.36	9.96	10.36
е	2.54TYP		2.54 BSC	
F	2.34	2.76	2.34	2.74
G	6.50	6.90	6.48	6.88
L	12.37	12.77	12.78	13.18
L1	2.23	2.63	3.03	3.43
Q	2.56	2.96	2.56	2.96
Q1	3.10	3.50	3.10	3.50
ØR	2.98	3.38	3.08	3.28

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A:10.20	± 0.50	B:15.90	± 0.50	C:29.00	± 1.00	D:1.24	±0.10
E:0.80	± 0.10	F:2.54	± 0.10	G:13.10	$\pm 1,0$	H:2.55	± 0.05
I:4.70	±0.05	J:0.50	± 0.05	K:1.20	± 0.20	L:8.00	±0.50
M:3.00	± 0.50	N:3.20	± 0.20	O:1,25	± 0.05	P:1.5	± 0.05
Q:1.0	±0.20	R:19.2	±1.0				

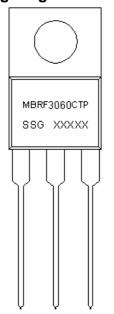
OPTION 5 (SR)

ITO-220AB



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Marking Diagram:



Where XXXXX is YYWWL

MBR = Device Type F = Package type

30 = Forward Current (30A) 60 = Reverse Voltage (60V)

CTP = Configuration

SSG = SSG YY = Year WW = Week L = Lot Number

Cautions: Molding resin

Epoxy resin UL:94V-0

Ordering Information:

Device	Package	Shipping
MBRF3060CTP	ITO-220AB	FOrce / tube
MDKF3000C1P	(Pb-Free)	50pcs / tube

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification.

Maximum Ratings:

Characteristics	Symbol	Condition	Max.	Units
Peak Inverse Voltage	V_{RWM}	-	60	V
Max. Average Forward Current	I _{F(AV)}	50% duty cycle @T _C = 95℃, rectangular wave form	30	А
Max. Peak One Cycle Non- Repetitive Surge Current (per leg)	I _{FSM}	8.3 ms, half Sine pulse	200	A

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Electrical Characteristics:

Characteristics	Symbol	Condition	Max.	Units
Max. Forward Voltage Drop	V_{F1}	@ 15A, Pulse, T _J = 25 °C	0.77	V
(per leg)*	V_{F2}	@ 15 A, Pulse, T _J = 125 °C	0.67	V
Max. Reverse Current (per leg)*	I _{R1}	$@V_R = \text{rated } V_R$ $T_J = 25 ^{\circ}C$	1.0	mA
	I _{R2}	$@V_R = \text{rated } V_R$ $T_J = 125 ^{\circ}\text{C}$	100	mA
Max. Junction Capacitance (per leg)	C_T	$@V_R = 5V, T_C = 25 °C$ $f_{SIG} = 1MHz$	700	pF
Max. Voltage Rate of Change	dv/dt	-	10,000	V/μs
RSM Isolation Voltage (t = 1.0 second, R. H. < =30%, T _A = 25 °C)	$V_{\rm ISO}$	Clip mounting, the epoxy body away from the heatsink edge by more than 0.110" along the lead direction.	4500	- v
	V ISO	Clip mounting, the epoxy body is inside the heatsink.	3500	
		Screw mounting, the epoxy body is inside the heatsink.	1500	

^{*} Pulse Width < 300µs, Duty Cycle <2%

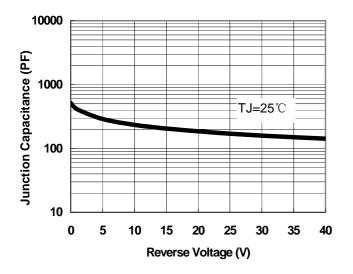
Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	Specification	Units
Max. Junction Temperature	TJ	-	-55 to +150	°C
Max. Storage Temperature	T _{stg}	-	-55 to +150	°C
Maximum Thermal Resistance Junction to Case	$R_{ heta JC}$	DC operation	3.0	°C/W
Maximum Thermal Resistance, Case to Heat Sink	$R_{ hetaJA}$	DC operation	60	°C/W
Approximate Weight	wt	-	2	g
Case Style		ITO-220AB		

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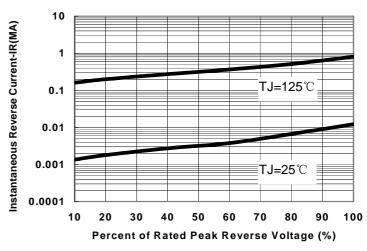


Fig.1-Typical Junction Capacitance

Fig.2-Typical Reverse Characteristics

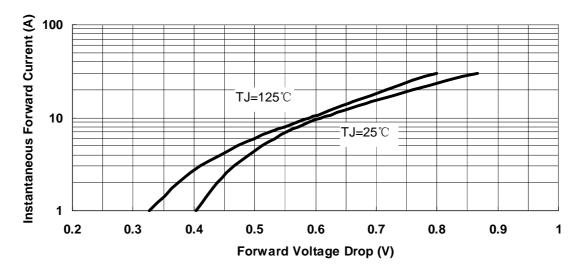


Fig.3-Typical Instantaneous Forward Voltage Characteristics

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MBRF3060CTP

Technical Data Data Sheet N0125, Rev. A **Green Products**

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